# 2.5 V / 3.3 V / 5.0 V 1:4 Clock Fanout Buffer

### Description

The NB3L553 is a low skew 1-to 4 clock fanout buffer, designed for clock distribution in mind. The NB3L553 specifically guarantees low output-to-output skew. Optimal design, layout and processing minimize skew within a device and from device to device.

#### **Features**

- Input/Output Clock Frequency up to 200 MHz
- Low Skew Outputs (35 ps), Typical
- RMS Phase Jitter (12 kHz 20 MHz): 29 fs (Typical)
- Output goes to Three-State Mode via OE
- Operating Range:  $V_{DD} = 2.375 \text{ V}$  to 5.25 V
- 5 V Tolerant Input Clock I<sub>CLK</sub>
- Ideal for Networking Clocks
- Packaged in 8-pin SOIC
- Industrial Temperature Range
- These are Pb-Free Devices

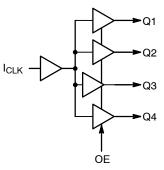


Figure 1. Block Diagram



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#### **MARKING DIAGRAMS\***



SOIC-8 D SUFFIX CASE 751



3L553 = Specific Device Code A = Assembly Location

L = Wafer Lot
Y = Year
W = Work Week
= Pb-Free Package



### DFN8 MN SUFFIX CASE 506AA



6P = Specific Device Code

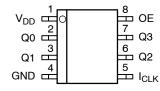
M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

\*For additional marking information, refer to Application Note AND8002/D.

#### PINOUT DIAGRAM



#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NB3L553DG	SOIC-8 (Pb-Free)	98 Units/Rail
NB3L553DR2G	SOIC-8 (Pb-Free)	2500/Tape & Reel
NB3L553MNR4G*	DFN-8 (Pb-Free)	1000/Tape & Reel

<sup>\*</sup>Contact Sales Representative

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Table 1. OE, OUTPUT ENABLE FUNCTION

OE	Function
0	Disable
1	Enable

## **Table 2. PIN DESCRIPTION**

Pin #	Name	Туре	Description		
1	$V_{DD}$	Power	Positive supply voltage (2.375 V to 5.25 V)		
2	Q0	(LV)CMOS/(LV)TTL Output	Clock Output 0		
3	Q1	(LV)CMOS/(LV)TTL Output	Clock Output 1		
4	GND	Power	Negative supply voltage; Connect to ground, 0 V		
5	I <sub>CLK</sub>	(LV)CMOS Input	Clock Input. 5.0 V tolerant		
6	Q2	(LV)CMOS/(LV)TTL Output	Clock Output 2		
7	Q3	(LV)CMOS/(LV)TTL Output	Clock Output 3		
8	OE	(LV)TTL Input	$V_{DD}$ for normal operation. Pin has no internal pullup or pull down resistor for open condition default. Use from 1 to 10 kOhms external resistor to force an open condition default state.		
-	EP	Thermal Exposed Pad	(DFN8 only) Thermal exposed pad must be connected to a sufficient thermal conduit. Electrically connect to the most negative supply (GND) or leave unconnected, floating open.		

**Table 3. MAXIMUM RATINGS** 

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>DD</sub>	Positive Power Supply	GND = 0 V	-	6.0	V
VI	Input Voltage	OE I <sub>CLK</sub>	GND = 0 V and V <sub>DD</sub> = 2.375 V to 5.25 V	$\begin{aligned} & \text{GND} - 0.5 \leq V_{\text{I}} \leq V_{\text{DD}} + 0.5 \\ & \text{GND} - 0.5 \leq V_{\text{I}} \leq 5.75 \end{aligned}$	V
T <sub>A</sub>	Operating Temperature Range, Industrial	-	_	≥ -40 to ≤ +85	°C
T <sub>stg</sub>	Storage Temperature Range	-	-	-65 to +150	°C
θJA	Thermal Resistance (Junction–to–Ambient)	0 Ifpm 500 Ifpm	SOIC-8	190 130	°C/W
θ <sub>JC</sub>	Thermal Resistance (Junction-to-Case)	(Note 1)	SOIC-8	41 to 44	°C/W
θЈА	Thermal Resistance (Junction–to–Ambient)	0 Ifpm 500 Ifpm	DFN8 DFN8	129 84	°C/W
θJC	Thermal Resistance (Junction-to-Case)	(Note 1)	DFN8	35 to 40	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

**Table 4. ATTRIBUTES** 

Charac	Value				
ESD Protection	Human Body Model Machine Model Charged Device Model	> 2 kV > 150 V > TBD kV			
Moisture Sensitivity, Indefinite Ti	Level 1				
Flammability Rating	Oxygen Index: 28 to 34	UL-94 code V-0 @ 0.125 in			
Transistor Count	531 Devices				
Meets or Exceeds JEDEC Standard EIA/JESD78 IC Latchup Test					

<sup>2.</sup> For additional Moisture Sensitivity information, refer to Application Note AND8003/D.

<sup>1.</sup> JEDEC standard multilayer board - 2S2P (2 signal, 2 power)

Table 5. DC CHARACTERISTICS ( $V_{DD}$  = 2.375 V to 2.625 V, GND = 0 V,  $T_A$  = -40°C to +85°C) (Note 3)

Symbol	Characteristic	Min	Тур	Max	Unit
I <sub>DD</sub>	Power Supply Current @ 135 MHz, No Load	=	25	30	mA
V <sub>OH</sub>	Output HIGH Voltage – I <sub>OH</sub> = –16 mA	1.7	=	-	V
V <sub>OL</sub>	Output LOW Voltage – I <sub>OL</sub> = 16 mA	=	=	0.4	V
V <sub>IH,</sub> I <sub>CLK</sub>	Input HIGH Voltage, I <sub>CLK</sub>	(V <sub>DD</sub> ÷2)+0.5	-	5.0	V
V <sub>IL,</sub> I <sub>CLK</sub>	Input LOW Voltage, I <sub>CLK</sub>	-	-	(V <sub>DD</sub> ÷2)-0.5	V
V <sub>IH,</sub> OE	Input HIGH Voltage, OE	1.8	-	$V_{DD}$	V
V <sub>IL,</sub> OE	Input LOW Voltage, OE	-	-	0.7	V
ZO	Nominal Output Impedance	-	20	-	Ω
CIN	Input Capacitance, I <sub>CLK</sub> , OE	-	5.0	-	pF
IOS	Short Circuit Current	=	± 28	_	mA

## **DC CHARACTERISTICS** ( $V_{DD}$ = 3.15 V to 3.45 V, GND = 0 V, $T_A$ = -40°C to +85°C) (Note 3)

Symbol	Characteristic	Min	Тур	Max	Unit
I <sub>DD</sub>	Power Supply Current @ 135 MHz, No Load	-	35	40	mA
V <sub>OH</sub>	Output HIGH Voltage – I <sub>OH</sub> = -25 mA	2.4	-	-	٧
V <sub>OL</sub>	Output LOW Voltage – I <sub>OL</sub> = 25 mA	-	-	0.4	٧
V <sub>OH</sub>	Output HIGH Voltage – I <sub>OH</sub> = –12 mA (CMOS level)	V <sub>DD</sub> – 0.4	-	-	٧
V <sub>IH,</sub> I <sub>CLK</sub>	Input HIGH Voltage, I <sub>CLK</sub>	(V <sub>DD</sub> ÷2)+0.7	-	5.0	٧
V <sub>IL,</sub> I <sub>CLK</sub>	Input LOW Voltage, I <sub>CLK</sub>	_	-	(V <sub>DD</sub> ÷2)-0.7	٧
V <sub>IH,</sub> OE	Input HIGH Voltage, OE	2.0	-	$V_{DD}$	٧
V <sub>IL,</sub> OE	Input LOW Voltage, OE	0	_	0.8	V
ZO	Nominal Output Impedance	_	20	-	Ω
CIN	Input Capacitance, OE		5.0	_	pF
IOS	Short Circuit Current	_	± 50	_	mA

## **DC CHARACTERISTICS** (V<sub>DD</sub> = 4.75 V to 5.25 V, GND = 0 V, $T_A$ = -40°C to +85°C) (Note 3)

Symbol	Characteristic	Min	Тур	Max	Unit
I <sub>DD</sub>	Power Supply Current @ 135 MHz, - No Load	-	45	85	mA
V <sub>OH</sub>	Output HIGH Voltage – I <sub>OH</sub> = –35 mA	2.4	_	-	V
V <sub>OL</sub>	Output LOW Voltage – I <sub>OL</sub> = 35 mA	-	-	0.4	V
V <sub>OH</sub>	Output HIGH Voltage – I <sub>OH</sub> = –12 mA (CMOS level)	V <sub>DD</sub> - 0.4	-	-	V
V <sub>IH,</sub> I <sub>CLK</sub>	Input HIGH Voltage, I <sub>CLK</sub>	(V <sub>DD</sub> ÷2) + 1	-	5.0	V
V <sub>IL,</sub> I <sub>CLK</sub>	Input LOW Voltage, I <sub>CLK</sub>	-	-	(V <sub>DD</sub> ÷2) – 1	V
V <sub>IH,</sub> OE	Input HIGH Voltage, OE	2.0	-	$V_{DD}$	V
V <sub>IL,</sub> OE	Input LOW Voltage, OE	-	-	0.8	V
ZO	Nominal Output Impedance	-	20	-	Ω
CIN	Input Capacitance, OE	-	5.0	-	pF
IOS	Short Circuit Current	-	± 80	-	mA

**Table 6. AC CHARACTERISTICS; V\_{DD} = 2.5 V ±5% (V\_{DD} = 2.375 V to 2.625 V, GND = 0 V, T\_{A} = -40°C to +85°C) (Note 3)** 

Symbol	Characteristic	Min	Тур	Max	Unit
f <sub>in</sub>	Input Frequency	-	-	200	MHz
t <sub>r</sub> /t <sub>f</sub>	Output rise and fall times; 0.8 V to 2.0 V	-	1.0	1.5	ns
t <sub>pd</sub>	Propagation Delay, CLK to Q <sub>n</sub> (Note 4)	2.2	3.0	5.0	ns
t <sub>skew</sub>	Output-to-output skew; (Note 5)	-	35	50	ps
t <sub>skew</sub>	Device-to-device skew, (Note 5)	-	-	500	ps

## AC CHARACTERISTICS; $V_{DD}$ = 3.3 V ±5% ( $V_{DD}$ = 3.15 V to 3.45 V, GND = 0 V, $T_A$ = -40°C to +85°C) (Note 3)

Symbol	Characteristic	Conditions	Min	Тур	Max	Unit
f <sub>in</sub>	Input Frequency		-	-	200	MHz
t <sub>jitter</sub> (φ)	RMS Phase Jitter (Integrated 12 kHz – 20 MHz) (See Figures 2 and 3)	f <sub>carrier</sub> = 100 MHz	-	18	-	fs
t <sub>r</sub> /t <sub>f</sub>	Output rise and fall times; 0.8 V to 2.0 V		-	0.6	1.0	ns
t <sub>pd</sub>	Propagation Delay, CLK to Q <sub>n</sub> (Note 4)		2.0	2.4	4.0	ns
t <sub>skew</sub>	Output-to-output skew; (Note 5)		-	35	50	ps
t <sub>skew</sub>	Device-to-device skew, (Note 5)		ı	ı	500	ps

## $\textbf{AC CHARACTERISTICS; V}_{DD} = \textbf{5.0 V} \pm \textbf{5\%} \ (V_{DD} = 4.75 \ V \ to \ 5.25 \ V, \ GND = 0 \ V, \ T_{A} = -40 ^{\circ} C \ to \ +85 ^{\circ} C) \ (Note \ 3)$

Symbol	Characteristic	Min	Min	Тур	Max	Unit
f <sub>in</sub>	Input Frequency		-	-	200	MHz
t <sub>jitter</sub> (φ)	RMS Phase Jitter (Integrated 12 kHz – 20 MHz) (See Figures 2 and 3)	f <sub>carrier</sub> = 100 MHz	-	29	-	fs
t <sub>r</sub> /t <sub>f</sub>	Output rise and fall times; 0.8 V to 2.0 V		-	0.3	0.7	ns
t <sub>pd</sub>	Propagation Delay, CLK to Q <sub>n</sub> (Note 4)		1.7	2.5	4.0	ns
t <sub>skew</sub>	Output-to-output skew; (Note 5)		-	35	50	ps
t <sub>skew</sub>	Device-to-device skew, (Note 5)		-	-	500	ps

<sup>3.</sup> Outputs loaded with external  $R_L = 33 \Omega$  series resistor and  $C_L = 15 pF$  to GND for proper operation. Duty cycle out = duty in. A 0.01  $\mu$ F decoupling capacitor should be connected between V<sub>DD</sub> and GND.

<sup>4.</sup> Measured with rail-to-rail input clock
5. Measured on rising edges at V<sub>DD</sub> ÷ 2 between any two outputs with equal loading.

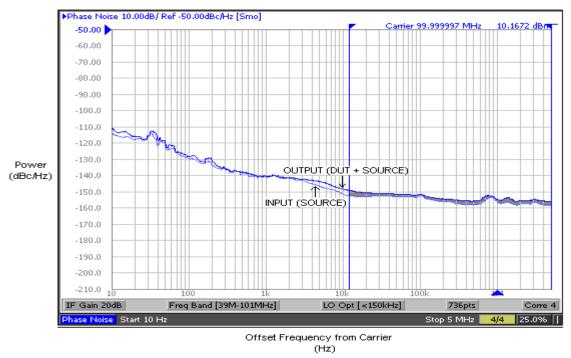


Figure 2. Phase Noise Plot at 100 MHz at an Operating Voltage of 3.3 V, Room Temperature

The above plot captured using Agilent E5052A shows Additive Phase Noise of the NB3L553 device measured with an input source generated by Agilent E8663B. The RMS phase jitter contributed by the device (integrated between 12 kHz to 20 MHz; as shown in the shaded area) is 18 fs (RMS Phase Jitter of the input source is 75.40 fs and Output (DUT+Source) is 93.16 fs).

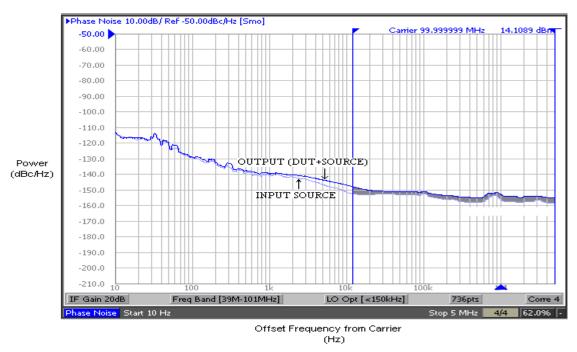
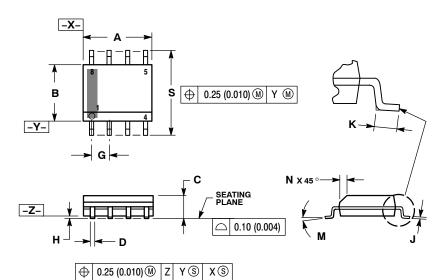


Figure 3. Phase Noise Plot at 100 MHz at an Operating Voltage of 5 V, Room Temperature

The above plot captured using Agilent E5052A shows Additive Phase Noise of the NB3L553 device measured with an input source generated by Agilent E8663B. The RMS phase jitter contributed by the device (integrated between 12 kHz to 20 MHz; as shown in the shaded area) is 29 fs (RMS Phase Jitter of the input source is 75.40 fs and Output (DUT+Source) is 103.85 fs).

### PACKAGE DIMENSIONS

### SOIC-8 NB CASE 751-07 **ISSUE AJ**

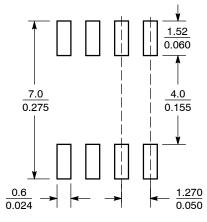


#### NOTES:

- TIES:
  DIMENSIONING AND TOLERANCING PER
  ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  DIMENSION A AND B DO NOT INCLUDE
  MOLD PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 (0.006)
  PER SIDE
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006)
  PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR
  PROTRUSION. ALLOWABLE DAMBAR
  PROTRUSION SHALL BE 0.127 (0.005) TOTAL
  IN EXCESS OF THE D DIMENSION AT
  MAXIMUM MATERIAL CONDITION.
  6. 751-01 THRU 751-06 ARE OBSOLETE. NEW
  STANDARD IS 751-07.

	MILLIMETERS		INC	HES
DIM	MIN	MIN MAX		MAX
Α	4.80	5.00	0.189	0.197
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27	BSC	0.050 BSC	
Н	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
М	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

## **SOLDERING FOOTPRINT\***

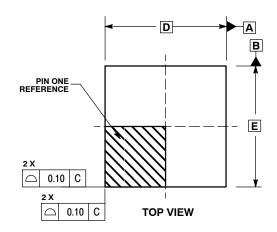


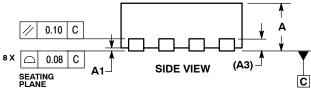
(mm inches SCALE 6:1

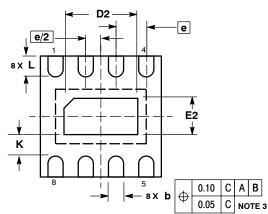
<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

### DFN8 CASE 506AA-01 ISSUE D







**BOTTOM VIEW** 

#### NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
   CONTROLLING DIMENSION: MILLIMETERS.
- CONTROLLING DIMENSION: MILLIMETERS
   DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN
- TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
  4. COPLANARITY APPLIES TO THE EXPOSED
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS	
DIM	MIN	MAX
Α	0.80	1.00
A1	0.00	0.05
A3	0.20 REF	
b	0.20	0.30
D	2.00 BSC	
D2	1.10	1.30
Е	2.00 BSC	
E2	0.70	0.90
е	0.50 BSC	
K	0.20	
L	0.25	0.35

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